



# **SNS COLLEGE OF ENGINEERING**

**Coimbatore-641 107**

**( An Autonomous Institution )**

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Approved by AICTE, New Delhi & Recognized by UGC

Affiliated to Anna University, Chennai

**DEPARTMENT OF PHYSICS**

**COURSE NAME :23PYT101 – ENGINEERING PHYSICS**

**I YEAR / I SEMESTER**

**UNIT 2 – LASER AND FIBER OPTICS**

**TOPIC 5 – SEMICONDUCTOR LASER AND IT'S APPLICATION**





# Introduction of Semi conductor laser



- **Semiconductor lasers** are solid-state lasers based on semiconductor gain media.
- A **semiconductor laser (LD)** is a device that causes **laser** oscillation by flowing an electric current to **semiconductor**.
- The mechanism of light emission is the same as a light-emitting diode (LED).
- When the two meet at the junction, an electron drops into a hole and light is emitted at the time.





Electroluminescence is the basic principle behind the operation of a semiconductor laser.

Semiconductors are classified in two types:

1. Direct band and
2. Indirect band

In direct band semiconductors the recombination's of an electron and a hole take place directly there by emitting photons. It's used for laser action.

1. Homo junction laser
2. Hetero junction laser

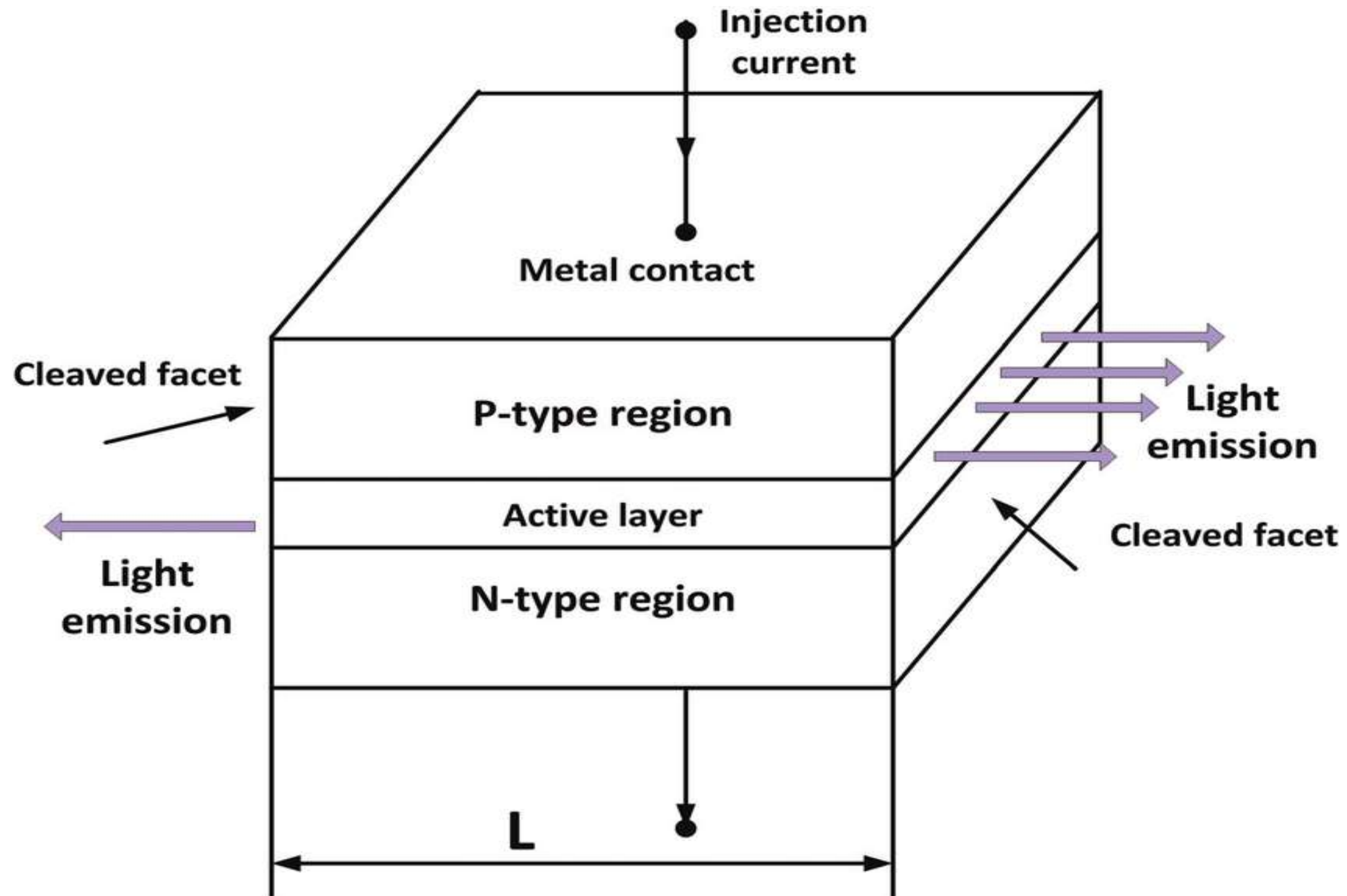


## Homo junction semi conductor laser



### **Construction:**

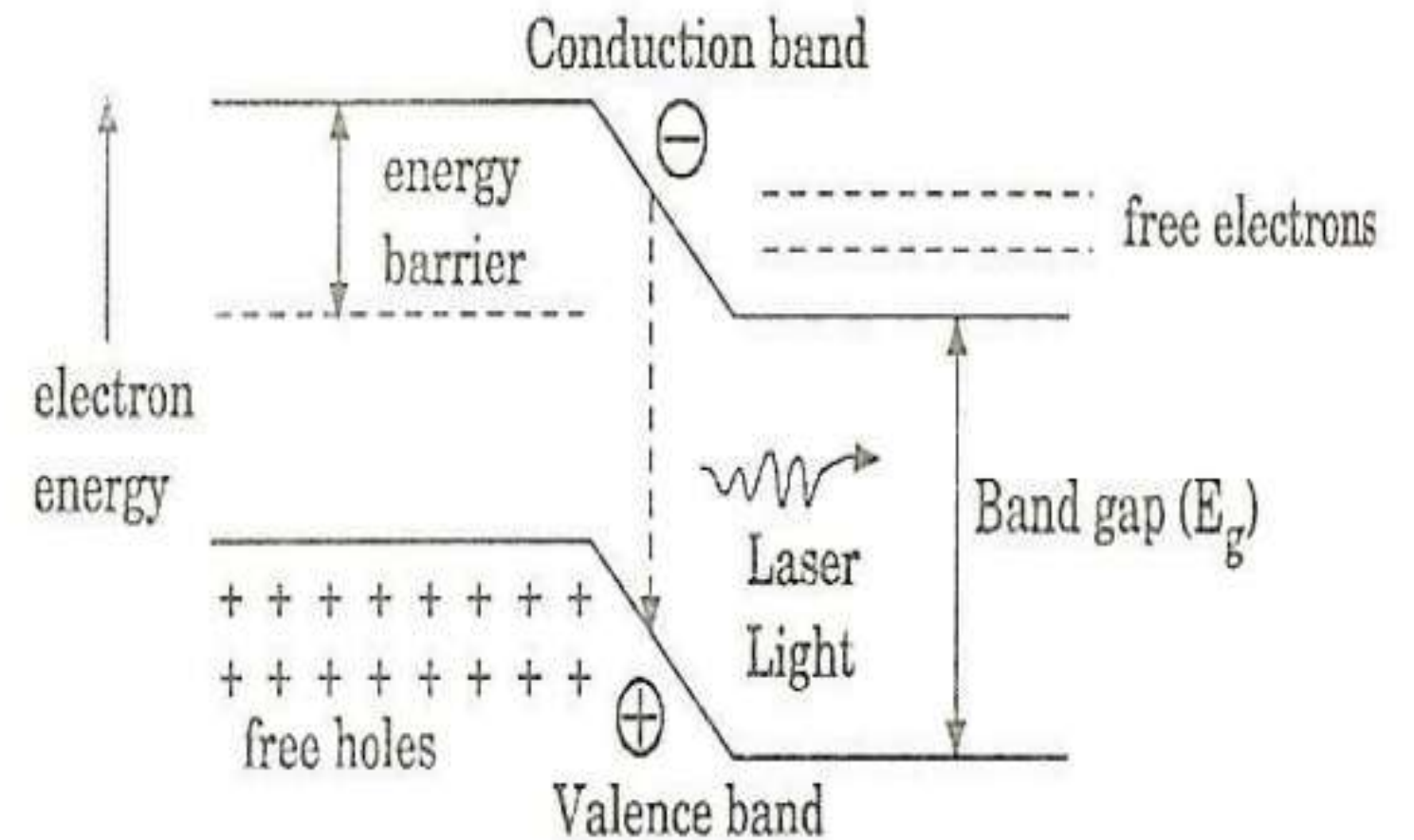
- The active medium is a p-n junction made from GaAs.
- The p-region and n-region in the diode are obtained by doping germanium (Ge) and tellurium (Te) respectively in GaAs.
- The thickness of the p-n junction layer is made very thin, typically of the order of few microns and the end faces of the crystal are made partially reflecting to form an optical resonator.
- Electric current is applied to the crystal through metal electrodes fixed on its upper and lower surface.





## Energy level diagram

- The population inversion is achieved by injecting  $e^-$ s across the junction from the n-region to the p-region by the mean of a forward biasing voltage applied across it.
- The recombination of  $e^-$ s and holes in the region result in the emission of photons.
- The process is spontaneous and the laser radiation is random and incoherent.





- But these photons triggers the stimulated emission of photons to get generated by increasing the rate of recombination of  $e^-$  s and holes.
- The current density is increased the emission becomes more and more coherent and the radiation intensity increase.
- The wavelength of the emitted light radiation depends upon the concentration of donor and acceptor atoms in GaAs and also on the energy gap of the particular semiconductor.



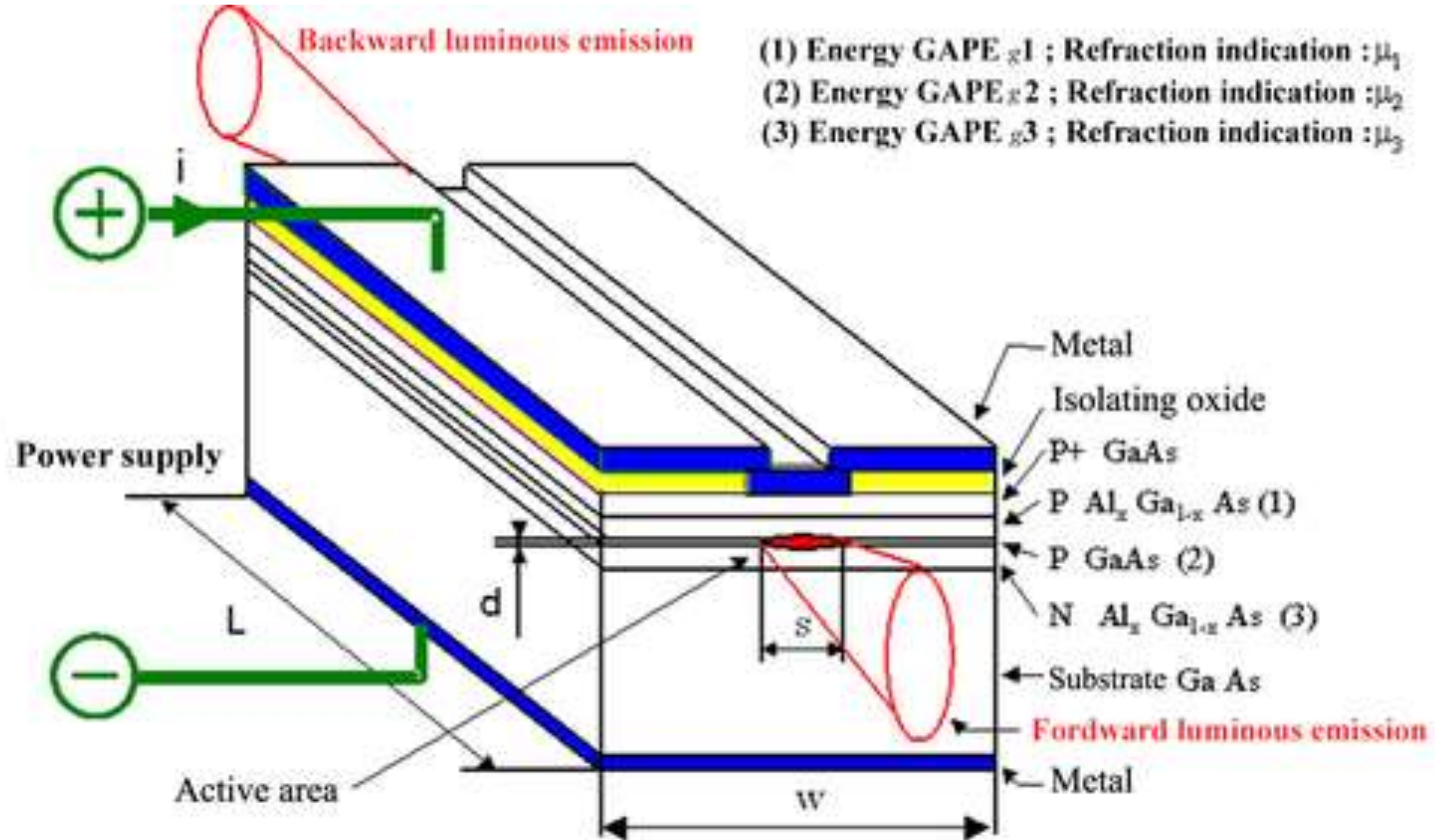
## Assignment

1. What is the principle of semiconductor laser?
2. Distinguish between homojunction and heterojunction?
3. Why gallium arsenide is used for semiconductor laser?





# Homo junction semi conductor laser





- Hetero junction laser have high efficiency even at room temperature.
- It is composed of various doping combinations of GaAs and AlGaAs.
- The p-layer of GaAs has an active region that is only 0.1-0.2  $\mu\text{m}$  thick.
- AlGaAs layer on both side serve as potential barriers and provide confinement for charge carriers to flow with in the active region.
- The excitation and recombination radiation can occur only with in the active region.
- Due to multilayer in the laser structure carriers are confined to a narrow region, the population is built up at lower current level.



- The operating current level is less than 50mA and the output power is 10mW.
- The light emitting at wavelength in the active region 1.1 to 1.6  $\mu\text{m}$  is desirable.

### **Characteristics:**

1. Type: It is a solid state semiconductor laser.
2. Active centre: p-n junction diode made from a single crystal of GaAs.
3. Pumping method: Direct conversion method.
4. Power output: 10mW.
5. Nature of the output: Continuous (or) pulsed
6. Wavelength: 8300 to 8500  $\text{A}^0$





## Advantages of semiconductor laser

It is very small in dimension.

The arrangement is simple and compact.

It exhibits high efficiency.

## Disadvantages of semiconductor laser

The output is usually in the form of wide beam.

The purity & mono chromaticity are poorer than other type of laser.



# APPLICATION OF LASER







# References



- <https://images.app.goo.gl/5BtLju8WmoCNC49J7>
- <https://images.app.goo.gl/gWrcRWdamUCqG3LR7>
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*Thank You*